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**SIDDHARTH INSTITUTE OF ENGINEERING & TECHNOLOGY:: PUTTUR**  
**(AUTONOMOUS)**  
**B.Tech II Year I Semester (R16) Regular Examinations November 2017**  
**BASIC ELECTRONIC DEVICES**  
**(Common to ECE, EEE)**

Time: 3 hours

Max. Marks: 60

(Answer all Five Units 5 X 12 = 60 Marks)

**UNIT-I**

- 1 a Differentiate between ideal and practical diodes with examples 6M  
 b Write the ideal diode current–voltage relationship 6M

**OR**

- 2 With neat diagrams, explain forward and reverse biasing of a PN Junction diode Draw its V-I Characteristics 12M

**UNIT-II**

- 3 a Draw and explain the basic structure of LED. Mention the applications of LED. 6M  
 b Write notes on Liquid Crystal Display 6M

**OR**

- 4 a Draw the basic structure of an SCR. Explain its characteristics and list the applications. 6M  
 b Define Holding Current and Latching Current of SCR 6M

**UNIT-III**

- 5 a Draw the circuit diagram of half wave rectifier and explain its operation with the help of waveforms 6M  
 b A bridge rectifier is supplied directly from a 220-V (rms), 50-Hz source without any input transformer. The load resistance is  $R_L = 2k\Omega$ . Assume that the second harmonic is the dominant one 6M

**OR**

- 6 AHWR is supplied directly from a 220-V (rms), 50-Hz source without any input transformer. The load resistance is  $R_L = 1k\Omega$ . Assume that the second harmonic is the dominant one  
 a Design a Capacitor filter so that the rms ripple voltage  $V_{r(rms)}$  is limited to less than 5% of  $V_{o(av)}$  6M  
 b With the value of C found in part (a), calculate the average output voltage  $V_{o(av)}$ , and the capacitor voltage if the load resistance  $R_L$  is disconnected 6M

**UNIT-IV**

- 7 a Give the current components of PNP transistor and explain 6M  
b If the base current in a transistor is  $20\mu\text{A}$  when the emitter current is  $4\text{mA}$ , what are the values of  $\alpha$  and  $\beta$ ? Also calculate the collector current 6M

**OR**

- 8 a Discuss the operation and drain characteristics of n-channel depletion type MOSFET 6M  
b Design a CE amplifier with  $A_V=100$ ,  $I_C=3\text{mA}$ ,  $I_{C(\min)}=2.5\text{mA}$ ;  $I_{C(\max)}=3.5\text{mA}$ ,  $R_L=4.7\text{K}\Omega$ . The lower and upper cut-off frequency is  $500\text{Hz}$ . The parameters of BC107 transistor are  $h_{fe(\min)}=180$ ;  $h_{fe(\max)}=400$ . 6M

**UNIT-V**

- 9 Derive the relation between  $S(I_{co})$  and  $S(\beta)$  of a Self-bias circuit 12M

**OR**

- 10 a Describe Thermistor and Sensistor Compensation Techniques 6M  
b Discuss about Thermal Runaway and Thermal Resistance. 6M

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